MM74C911 4-Digit Expandable Segment Display Controller

General Description

FAIRCHILD

The MM74C911 display controller is an interface element with memory that drives a 4-digit, 8-segment LED display. The MM74C911 allows individual control of any segment in the 4-digit display. The number of segments per digit can be expanded without any external components. For example, two MM74C911's can be cascaded to drive a 16-segment alpha-numeric display.

The display controllers receive data information through 8 data lines a, b...DP, and digit information through 2 address inputs K1 and K2. The input data is written into the register selected by the address information when \overrightarrow{CHIP} ENABLE, \overrightarrow{CE} , and \overrightarrow{WRITE} ENABLE, \overrightarrow{WE} , are LOW and is latched when either \overrightarrow{CE} or \overrightarrow{WE} return HIGH. Data hold time is not required.

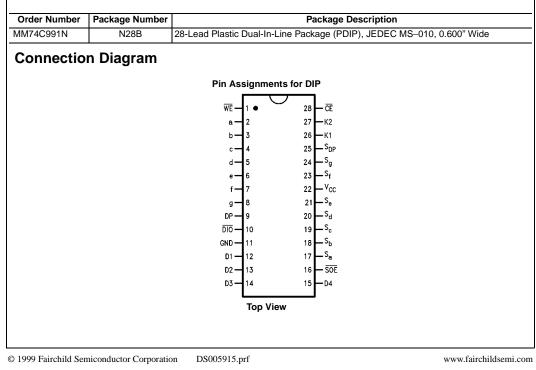
A self-contained internal oscillator sequentially presents the stored data to high drive (100 mA typ.) 3-STATE output drivers which directly drive the LED display. The drivers are active when the control pin labeled SEGMENT OUTPUT ENABLE, SOE, is LOW and go into 3-STATE when SOE is HIGH. This feature allows for duty cycle brightness control, or for disabling the output drive for power conservation. The digit outputs directly drive the base of the digit transistor when the control pin labeled $\overrightarrow{\text{DIGIT INPUT OUTPUT}}$, $\overrightarrow{\text{DIO}}$, is LOW. When $\overrightarrow{\text{DIO}}$ is HIGH, the digit lines turn into inputs and the internal scanning multiplexer is disabled.

When any digit line is forced HIGH by an external device, usually another MM74C911, the data information for that digit is presented to the output. In this manner, 16-segment alpha-numeric displays, 24- or 32-segment displays, or an array of discrete LED's can be controlled by the simple cascading of expandable segment display controllers. All inputs except digit inputs are TTL compatible and do not clamp input voltages above $V_{CC}. \end{tabular}$

Features

- Direct segment drive (100 mA typ.) 3-STATE
- 4 registers addressed like RAM
- Internal oscillator and scanning circuit
- Direct base drive to digit transistor
- Segment expandability without external components
- TTL compatible inputs
- Power saver mode—5 µW (typ.)

Ordering Code:



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MM74C911

Truth Tables

Input Control

CE	Digit Address		WE	Operation	
0L	K2 K1			operation	
0	0	0	0	Write Digit 1	
0	0	0	1	Latch Digit 1	
0	0	1	0	Write Digit 2	
0	0	1	1	Latch Digit 2	
0	1	0	0	Write Digit 3	
0	1	0	1	Latch Digit 3	
0	1	1	0	Write Digit 4	
0	1	1	1	Latch Digit 4	
1	Х	Х	х	Disable Writing	

Functional Description

The MM74C911 display controller is manufactured on standard metal gate CMOS technology. A single 5V 74 series TTL supply can be used for power and should be bypassed at the V_{CC} pin to suppress current transients.

The digit outputs directly drive the base of a grounded emitter digit transistor without the need of a Darlington configuration. If an MM74C911 is driving a digit transistor and also supplying digit information to a cascaded MM74C911, base resistors are needed in the digit transistors to provide an adequate high level to the digit inputs of the cascaded MM74C911.

As seen in the Block Diagram, these display controllers contain four 8-bit registers; any one may be randomly writ-

Output Control

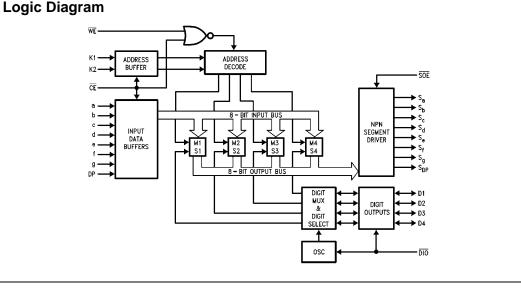
ĺ	DIO	SOE	Digit Lines		s	Operation	
			D4	D3	D2	D1	
	0	0	R	R	R	R	Refresh Display
	0	1	R	R	R	R	Disable Segment Outputs
	1	0	0	0	0	0	Digits Are Now Inputs
	1	0	0	0	0	1	Display Digit 1
	1	0	0	0	1	0	Display Digit 2
	1	0	0	1	0	0	Display Digit 3
	1	0	1	0	0	0	Display Digit 4
l	1	1	0	0	0	0	Power Saver Mode

$$\label{eq:R} \begin{split} &\mathsf{R} = \mathsf{R} \mathsf{e} \mathsf{f} \mathsf{r} \mathsf{e} \mathsf{s} \mathsf{h} \mbox{ (digit lines sequentially pulsed)} \\ &\mathsf{X} = \mathsf{D} \mathsf{o} \mathsf{n} \mathsf{'} \mathsf{t} \mbox{ Care} \end{split}$$

ten into. In normal operation, the internal multiplexer scans the registers and refreshes the display. In cascaded operation, 1 MM74C911 serves as a master refresh device and cascaded MM74C911's are slaved to it through digit lines operating as inputs.

The MM74C911 appears to a microprocessor as memory and to the user as a self-scan display. Since every segment is under microprocessor control, great versatility is obtained.

Low power standby operation occurs with both $\overline{\text{SOE}}$ and $\overline{\text{DIO}}$ inputs HIGH. This condition forces the MM74C911 to a quiescent state typically drawing less than 1 μ A of supply current with a standby supply voltage as low as 3V.



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Absolute Maximum Ratings(Note 1)		Operating V _{CC} Range 3V			
(Note 2)	U ()	Absolute Maximum V _{CC}	6.5V		
Voltage at Any Pin		Lead Temperature			
except Inputs	-0.3V to V _{CC} + 0.3V	(Soldering, 10 seconds)	260°C		
Voltage at Any Input		Note 1: "Absolute Maximum Ratings" are those v	values beyond which the		
except Digits	-0.3V to +15V	safety of the device cannot be guaranteed. Except for "Operating Range",			
Operating Temperature		they are not meant to imply that the device should its. The table of "Electrical Characteristics" provide			
Range, (T _A)	-40°C to +85°C	device operation.			
Storage Temperature Range	$-65^{\circ}C$ to $+150^{\circ}C$	Note 2: All voltage reference to ground.			
Power Dissipation (P _D)	Refer to $P_{D(MAX)}$ vs T_A Graph				

DC Electrical Characteristics

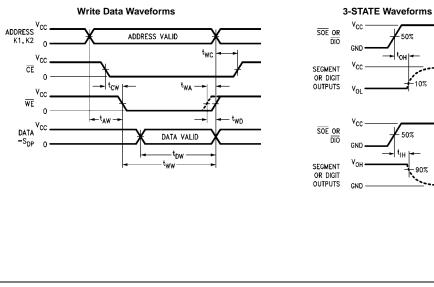
Symbol	Parameter	Conditions	Min	Тур	Max	Units
/ _{IN(1)}	Logical "1" Input Voltage	$V_{CC} = 5V$	3.0			V
/ _{IN(0)}	Logical "0" Input Voltage				1.5	V
IN(1)	Logical "1" Input Current	V _{CC} = 5V, V _{IN} = 15V		0.005	1.0	μA
IN(0)	Logical "0" Input Current	$V_{CC} = 5V, V_{IN} = 0V$	-1.0	-0.005		μΑ
сс	Supply Current (Normal)	V _{CC} = 5V, Outputs Open		0.50	2.5	mA
сс	Supply Current (Power Saver)	$V_{CC} = 5V$, \overline{SOE} , $\overline{DIO} = "1"$, D1, D2, D3, D4 = "0"		1	600	μΑ
I _{OUT}	3-STATE Output Current	V _O = 5V		0.03	10	μA
		$V_0 = 0V$	-10	-0.03		
CMOS/LP1	TL INTERFACE					
V _{IN(1)}	Logical "1" Input Voltage	$V_{CC} = 4.75V$	V _{CC} – 2			V
/ _{IN(0)}	Logical "0" Input Voltage	$V_{CC} = 4.75V$			0.8	V
OUTPUT D	RIVE		•			
I _{SH}	HIGH Level Segment Current	$V_{CC} = 5V, V_{O} = 3.4V$				
		$T_J = 25^{\circ}C$	-60	-100		mA
		$T_J = 100^{\circ}C$	-40	-60		mA
DH	HIGH Level Digit Current	$V_{CC} = 5V, V_{O} = 3V$				
		$T_J = 25^{\circ}C$	-10	-20		mA
		$T_J = 100^{\circ}C$	-7	-10		mA
		$V_{CC} = 5V, V_{O} = 1V$				
		$T_J = 25^{\circ}C$	-15	-40		mA
		$T_J = 100^{\circ}C$	-10	-15		mA
V _{OUT(1)}	Logical "1" Output Voltage,	$V_{CC} = 5V, I_{O} = -360 \ \mu A$	4.6			V
	Any Digit					
OUT(0)	Logical "0" Output Voltage,	$V_{CC} = 5V, I_{O} = 360 \ \mu A$			0.4	V
	Any Output					
JA	Thermal Resistance	(Note 3)		100		°C/W

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Symbol	Parameter	Conditions	Min	Тур	Max	Un
t _{cw}	Chip Enable to Write Enable Set-Up Time	T _{.1} = 25°C	35	15		n
CW		$T_{1} = 125^{\circ}C$	50	20		n
t _{AW}	Address to Write Enable Set-Up Time	$T_1 = 25^{\circ}C$	35	15		n
AVV		T ₁ = 125°C	50	20		n
tww	Write Enable Width	$T_J = 25^{\circ}C$	400	225		n
		$T_{1} = 125^{\circ}C$	450	250		n
t _{DW}	Data to Write Enable Set-Up Time	$T_1 = 25^{\circ}C$	390	225		n
-DVV		$T_{1} = 125^{\circ}C$	430	250		n
t _{WD}	Write Enable to Data Hold Time	T _{.1} = 25°C	0	-10		n
		T _{.1} = 125°C	0	-15		n
t _{WA}	Write Enable to Address Hold Time	T _J = 25°C	0	-10		n
		T _J = 125°C	0	-15		n
t _{WC}	Write Enable to Chip Enable Hold Time	$T_J = 25^{\circ}C$	55	30		n
		T _J = 125°C	75	40		n
t _{1H} , t _{0H}	Logical "1", Logical "0" Levels into 3-STATE	R _L =10k, C _L =10 pF				
		$T_J = 25^{\circ}C$		275	500	n
		$T_J = 125^{\circ}C$		325	600	n
t _{H1} , t _{H0}	3-STATE to Logical "1" or	R _L =10k, C _L =10 pF				
	Logical "0" Levels	$T_J = 25^{\circ}C$		325	600	n
		$T_J = 125^{\circ}C$		375	700	n
t _{D1} , t _{D0}	Propagation Delay from Digit Input to	$T_J = 25^{\circ}C$		500	1000	n
	Segment Output	$T_J = 125^{\circ}C$		700	1400	n
t _{IB}	Interdigit Blanking Time	$T_J = 25^{\circ}C$	5	10		μ
		$T_J = 125^{\circ}C$	10	20		μ
f _{MUX}	Multiplex Scan Frequency	$T_J = 25^{\circ}C$		525		н
		$T_J = 125^{\circ}C$		375		н
CIN	Input Capacitance	(Note 5)		5	7.5	р
COUT	3-STATE Output Capacitance	(Note 5)		30	50	р

Note 5: Capacitance guaranteed by periodic testing.

Switching Time Waveforms



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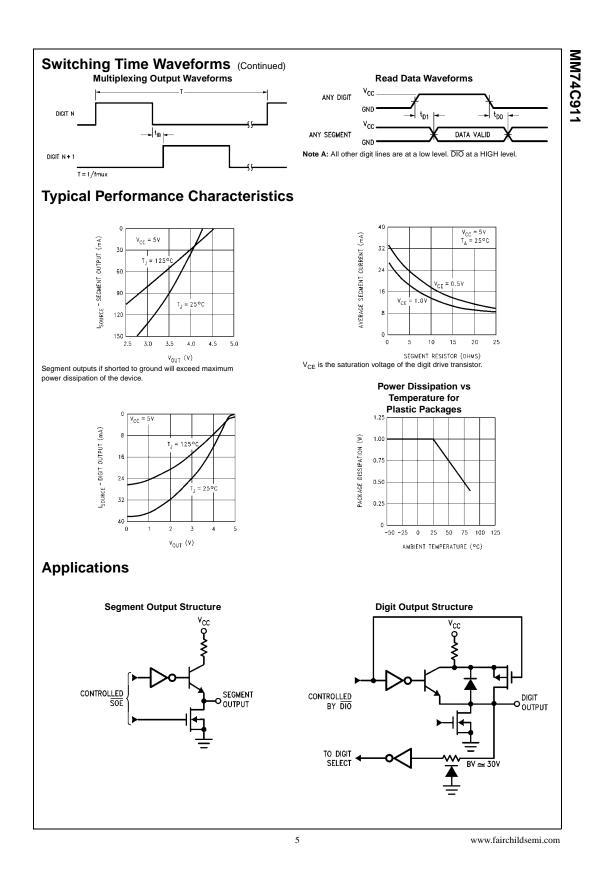
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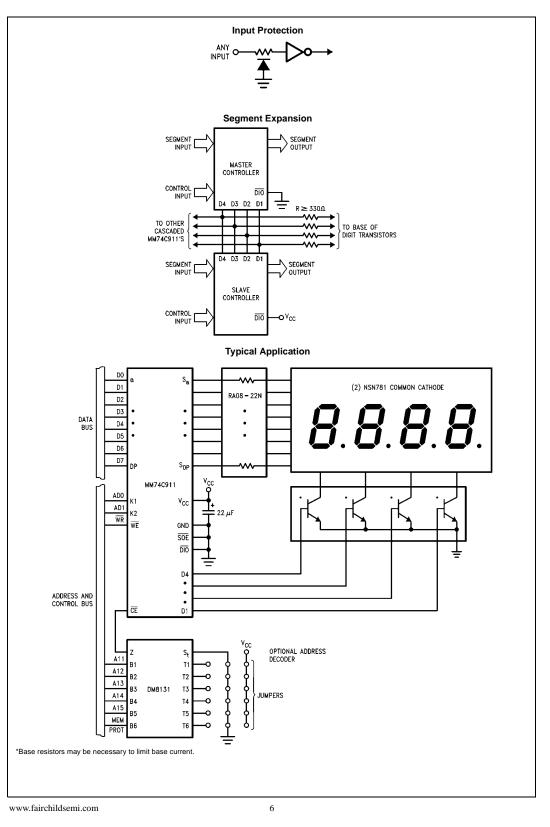
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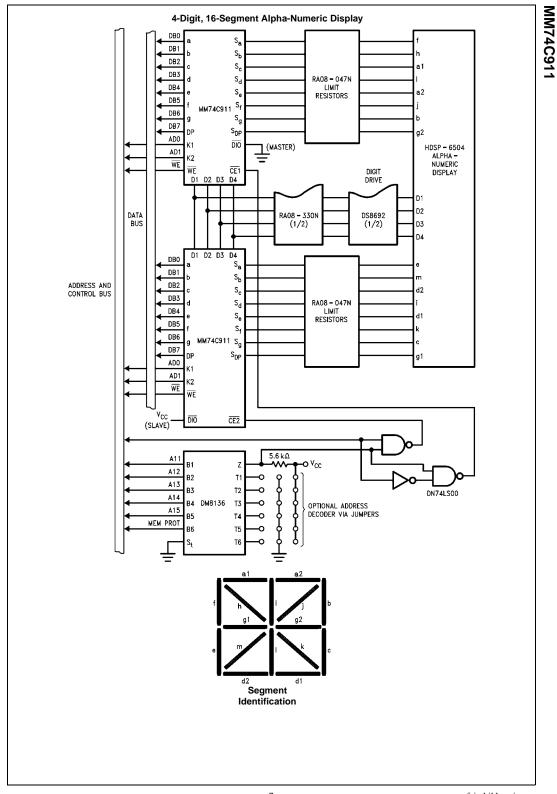
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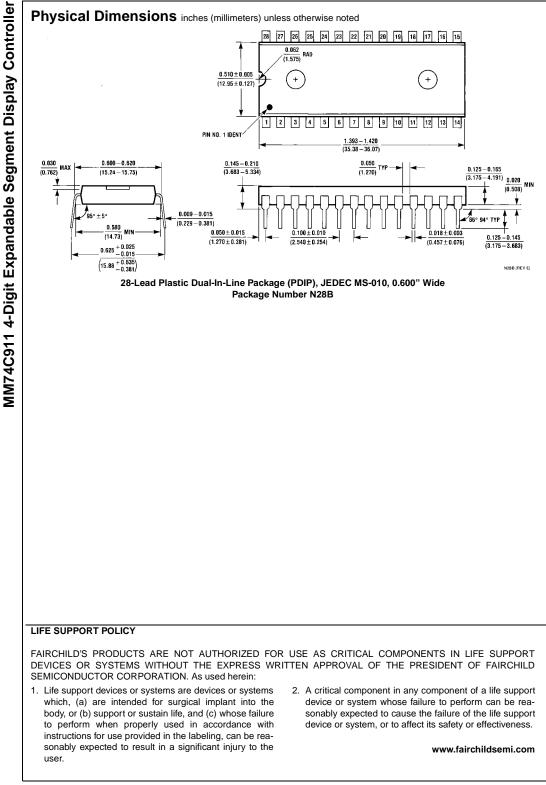


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